

# WCT-120 — The Standard Offline Wafer-Lifetime Tool



The WCT-120 is an affordable, tabletop silicon lifetime and wafer metrology system, suitable for both device research and industrial process control.

**Best available calibrated measurement of carrier recombination lifetime. Widely used for both monocrystalline and multicrystalline silicon wafers.**

## Product Overview

WCT testers showcase our unique measurement and analysis techniques, including the highly regarded Quasi-Steady-State Photoconductance (QSSPC) lifetime measurement method developed by Sinton Instruments in 1994. The QSSPC technique is ideal for monitoring multicrystalline wafers, dopant diffusions, and low-lifetime samples. This method complements the use of the transient photoconductance technique that is also standard on this instrument.

The QSSPC lifetime measurement also yields the implied open-circuit voltage (versus illumination) curve, which is comparable to an I-V curve at each stage of a solar cell process.

## WCT System Capabilities

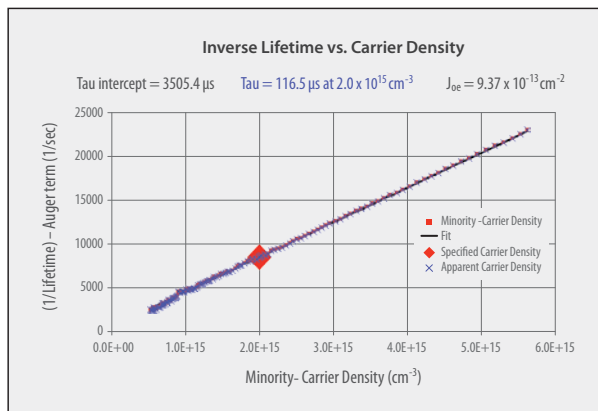
Primary application: Step-by-step monitoring and optimization of a fabrication process

Other applications:

- Monitoring initial material quality
- Detecting heavy metals contamination during wafer processing
- Evaluating surface passivation and emitter dopant diffusion
- Evaluating process-induced shunting using the implied I-V measurement

## Key Features

- Single-click identification of key characteristics of silicon wafers, including sheet resistance, lifetime, trap density, emitter saturation current density, and implied voltage
- Calibrated carrier-lifetime versus injection level yields results that are universally accepted



Sinton instruments' analysis yields a calibrated carrier injection level for each wafer, so you can interpret lifetime data in a physically precise way. Specific parameters of interest are displayed and logged for each measurement.

## WCT Specifications

### Instrument Specifications

#### Available measurements

- Lifetime
- Resistivity
- Emitter saturation current density
- Trap density
- One-sun Voc

#### Lifetime measurement range

- 100 ns to greater than 10 ms

#### Measurement (analysis) modes

- QSSPC, transient, and generalized lifetime analysis

#### Resistivity measurement range

- 3–600 (undoped) Ohms/sq.

#### Available light bias range

- 0–50 suns

#### Typical calibrated injection range

- $10^{13}$ – $10^{16}$  cm<sup>-3</sup>

#### Available spectrum

- White-light and IR illumination

#### Sensor area

- 40-mm diameter

#### Sample size, standard configuration

- Standard diameter: 40–210 mm
- Smaller sizes may be measured

#### Wafer thickness range

- 10–2000  $\mu$ m (calibrated)
- Other thicknesses may be measured

#### Warranty

- One-year limited warranty on all parts and software
- Service agreement also available



### Facility Requirements

#### Ambient operating temperature

- 20°C–25°C

#### Power requirements

- WCT-120: 40 W
- Computer with monitor: 200 W
- Light source: 60 W

#### Dimensions

- 22.5 cm W x 28 cm D x 57 cm H

#### Universal mains voltage

- 100–240 VAC 50/60 Hz

#### Special facilities requirements

None

### WCT System Components

- WCT-120 instrument, signal processing unit, signal cables
- Programmable flashlamp with bandpass filter
- Windows PC with installed, configured software and monitor
- Sinton Instruments data acquisition and analysis software package
- High-resolution, high-speed data acquisition with simultaneous sampling and common-mode rejection
- Optional Suns-Voc accessory

### Purchasing Information

For a quote, please contact  
quotes@sintoninstruments.com

We are happy to accommodate custom requirements. Please inquire about a quote for your specific needs.

Quotes are valid for 60 days. Please allow 10 weeks for delivery from date of purchase order.

For our full product line, visit our website at:  
www.sintoninstruments.com

